

Power Magnetics *@* **High Frequency** State-of-the-Art and Future Prospects

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Power Magnetics @ High Frequency State-of-the-Art and Future Prospects

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"Transforming Magnetics 'Black Magic' into Engineering"

A Workshop prior to APEC 2017 **Sponsored by the PSMA Magnetics Committee**

And

IEEE Power Electronics Society (PELS)

Saturday, March 25th, 2017 7:00 am -6:00 pm

Sessions

- AC Power Loss Measurements **Technology Demonstration**
 - **Technical Issues**

 - **AC Power Loss Modeling**





Outline

- Impact of Magnetics on Conv. Performance
- Losses Due to Stresses in Ferrite Surfaces
 The Ideal Switch is NOT Enough!
- Challenges in MV/MF Power Conversion
- **Future Prospects**

E. Hoene / FH IZM St. Hoffmann / FH IZM M. Kasper E. Hatipoqlu P. Papamanolis Th. Guillod J. Miniböck Acknowledgement U. Badstübner





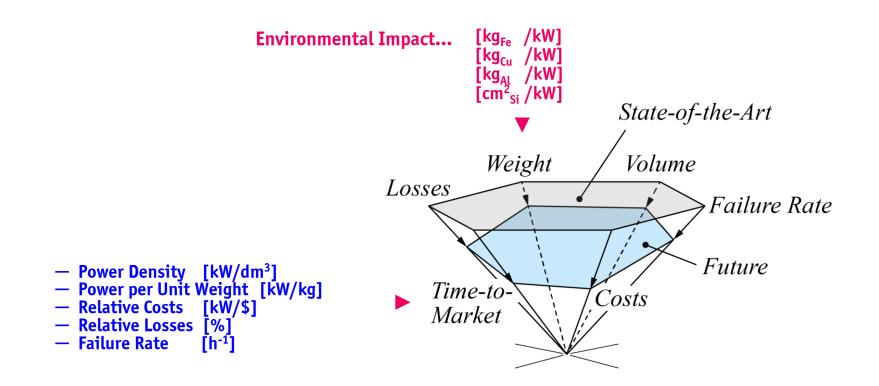
Introduction

Converter Performance Indicators Design Space / Performance Space





Power Electronics Converter Performance Indicators





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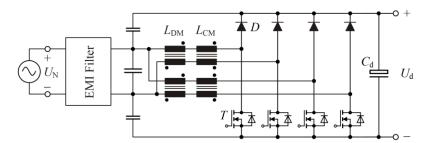
Performance Limits (1)

- Example of Highly-Compact 1-Φ PFC Rectifier
- Two Interleaved 1.6kW Systems





$$\star$$
 η = 95.8% @ ρ = 5.5 kW/dm³





→ High Power Density @ Low Efficiency
 → Trade-Off Between Power Density and Efficiency





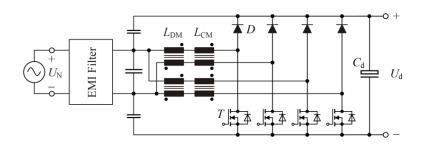
Performance Limits (2)

- Example of Highly-Efficient 1-⊕ PFC Rectifier
- Two Interleaved 1.6kW Systems

 $P_o = 3.2 \text{kW}$ $U_N = 230 \text{V} \pm 10\%$ $U_o = 365 \text{V}$

 $f_P = 33$ kHz \pm 3kHz

$$\star$$
 $\eta = 99.2\%$ @ $\rho = 1.1$ kW/dm³



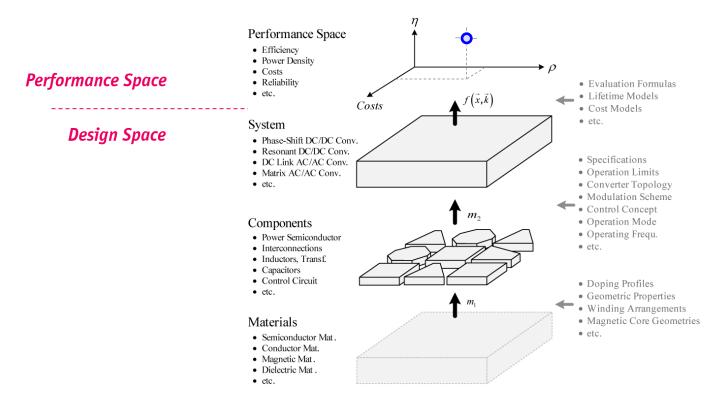
→ High Efficiency @ Low Power Density → Trade-Off Between Power Density and Efficiency







Abstraction of Power Converter Design



→ Mapping of "Design Space" into "Performance Space"



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Derivation of η-ρ-Performance Limit of Converter Systems

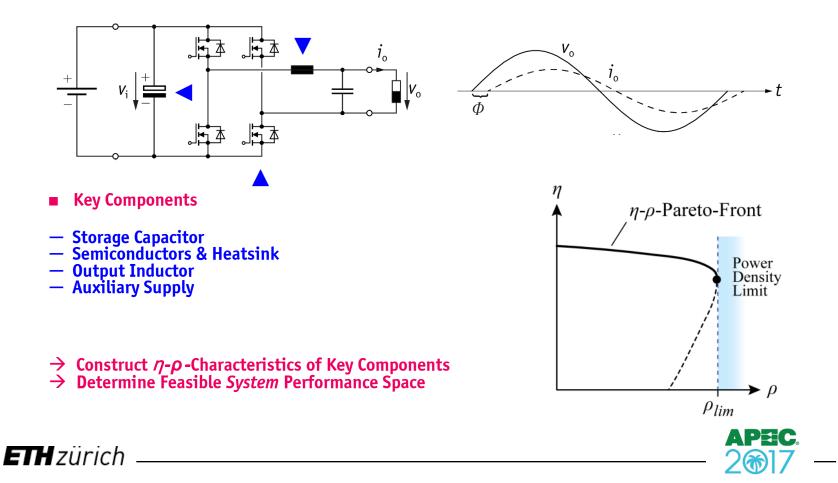
Component η - ρ -Characteristics Converter η - ρ -Pareto Front





• Derivation of the η - ρ -Performance Limit

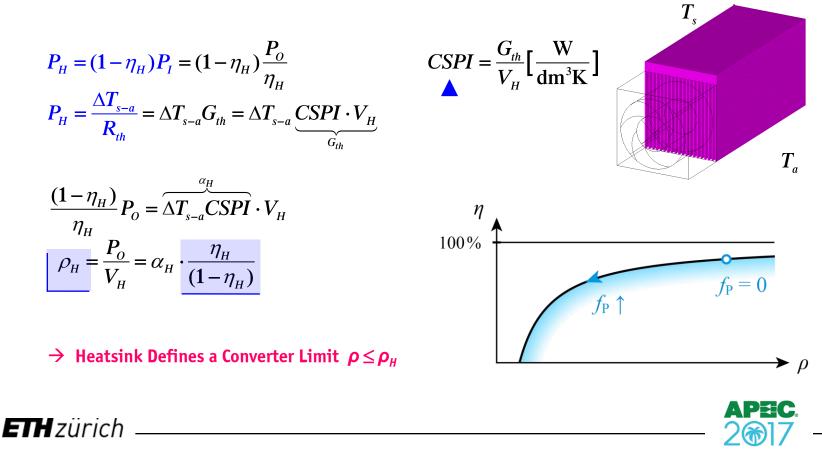
Example of DC/AC Converter System



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η-ρ-Characteristic of Power Semiconductors / Heatsink

- Semiconductor Losses are Translating into Heat Sink Volume
- Heatsink Characterized by <u>Cooling System Performance Index</u> (CSPI)
- Volume of Semiconductors Neglected



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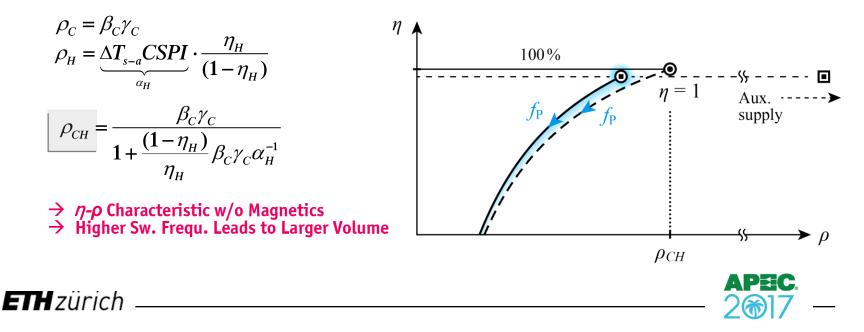
η-ρ-Characteristic of Storage+Heatsink+Auxiliary

- Overall Power Density Lower than Lowest Individual Power Density
- Total Efficiency Lower than Lowest Individual Efficiency

$$V = V_{C} + V_{H} + V_{aux} | \cdot \frac{1}{P_{0}} \qquad \rho_{i} = \frac{P_{0}}{V_{i}} \qquad P_{I} = P_{0} + \sum_{i} P_{i} = \frac{P_{0}}{\eta} \quad \Rightarrow \boxed{\eta} = \frac{1}{(1 + \frac{\sum_{i} P_{i}}{P_{0}})}$$

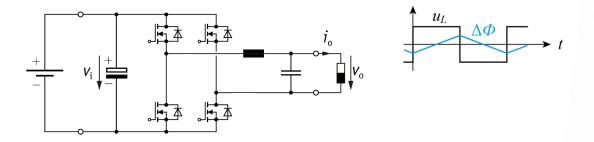
$$\rho_{i}^{-1} = \rho_{C}^{-1} + \rho_{H}^{-1} + \rho_{aux}^{-1}$$

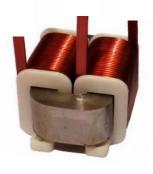
- Example of Heat Sink + Storage (No Losses)



• η - ρ -Characteristic of Inductor (1)

Inductor Flux Swing Defined by DC Voltage & Sw. Frequ. (& Mod. Index)





• "-1"-Order Approx. of Volume-Dependency of Losses

$$\Delta \hat{B} = \frac{U_{DC} \frac{1}{4} T_{P}}{NA_{E}} \propto \frac{U_{DC}}{f_{P} A_{E}} \propto \frac{1}{A_{E}} \propto \frac{1}{l^{2}} \rightarrow P_{E} \propto f_{P}^{\alpha} \Delta \hat{B}^{\beta} V_{E} \propto \approx (\frac{1}{l^{4}}) l^{3} \propto \frac{1}{l}$$

$$P_{W} = I_{rms}^{2} R_{W} \propto \frac{l}{\kappa A_{W}} \propto \frac{l}{l^{2}} \propto \frac{1}{l}$$

$$P_{W} = I_{rms}^{2} R_{W} \propto \frac{l}{\kappa A_{W}} \propto \frac{l}{l^{2}} \propto \frac{1}{l}$$

$$P_{L} = k_{\Sigma} V_{L}^{\frac{4(2-\beta)}{3(2+\beta)} - \frac{1}{3}} f_{P}^{\frac{2(\alpha-\beta)}{2+\beta}} I_{rms}^{\frac{2\beta}{2+\beta}} U_{DC}^{\frac{2\beta}{2+\beta}} |_{\beta=2}^{\alpha=1} \rightarrow \infty \frac{U_{DC}}{\sqrt{f_{R}}}$$

 \rightarrow Losses are Decreasing with Increasing Linear Dimensions & Sw. Frequency



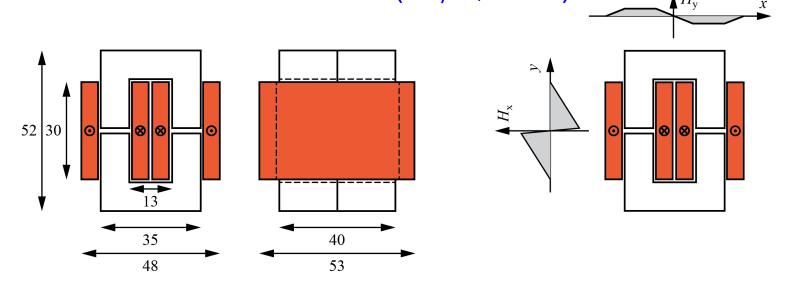
rms

αl

$\blacktriangleright \eta$ - ρ -Characteristic of Inductor (2)

- Minimization of the Losses of an Inductor of a 3 kW Step-Down DC/DC Converter
 - U₁= 400V / U₂ = 200V
 N87 Magnetic Cores

 - 71um Litz Wire Strand Diameter (35% Fill Factor)
 Consideration of HF Winding and Core Losses
 Thermal Limit Acc. to Natural Convection (0.1W/cm², 14W Total)



→ Calc. of Opt. # of Turns in Limits: $N \ge 1$, N_{min} Avoiding Sat. (incl. DC Curr.), N_{max} as for Air Core → HF Wdg. Losses: 2D Analy. Approx. / HF Core Losses: iGSE (DC Premagetization Not Consid.)







- Loss Minimiz. by Calculation of Opt. # of Turns Consideration of HF Winding and Core Losses Thermal Limit Acc. To Natural Convection

- Loss (W) 10^{0} **Assumption:** Given Magnetic Core Core Loss 10-1 10^{0} 10-1 10-2 10¹ 100kHz 10^{2} Natural Convection 1111 **Total Loss** Thermal Limit 10^{1} Loss (W) LF Winding Loss Core Loss 10^{0} HF Winding Loss 10^{2} 10- 10^{0} 10^{-1} 10^{-2} 10^{1} Total Loss (W) 1000kHz 10^{2} **....** 101 10^{4} Total Loss Switching Frequency (HP) LF Winding Loss 10^{1} Loss (W) Core Loss 10^{0} HF Winding Loss 10^{0} 10^{1} 1111 10^{0} 10- 10^{-1} 10-2 10^{0} 10¹ 10-1 10^{-2} Current Ripple (p.u.) Current Ripple (p.u.)

 \rightarrow Higher Sw. Frequ. – Lower Min. Ind. Losses – Overall Loss Red. Limited by Semicond. Sw. Losses



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10kHz

HF Winding Loss

Total Loss

/ T T T T T

LF Winding Loss

 10^{2}

 10^{1}

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$\blacktriangleright \eta$ - ρ -Characteristic of Inductor (3)

- Overall Power Density Lower than Lowest Individual Power Density
 Total Efficiency Lower than Individual Efficiency

$$P_{L} \propto \frac{U_{DC}I_{rms}}{\sqrt{f_{P}}V_{L}^{\frac{1}{3}}} \propto \frac{P_{O}}{\sqrt{f_{P}}V_{L}^{\frac{1}{3}}} (=k_{L,max}V_{L}^{\frac{2}{3}})$$

$$P_{L} = (1 - \eta_{L})P_{I} = (1 - \eta_{L})\frac{P_{O}}{\eta_{L}}$$

$$P_{L} = \frac{P_{O}}{V_{L}} \propto P_{O}f_{P}^{\frac{3}{2}}\frac{(1 - \eta_{L})^{3}}{\eta_{L}^{3}}$$

$$P_{L,max} \propto \sqrt{f_{P}}$$

$$\frac{P_{L,max}}{P_{L}} \propto \sqrt{f_{P}}$$

$$\frac{P_{L}}{P_{O}} = \frac{(1 - \eta_{L})}{\eta_{L}} \propto \frac{1}{\sqrt{f_{P}}V_{L}^{\frac{1}{3}}}$$

$$\frac{P_{L}}{P_{O}} \approx \frac{1}{\sqrt{f_{P}}V_{L}^{\frac{1}{3}}}$$

$$\frac{P_{L}}{P_{O}} \approx \frac{1}{\sqrt{f_{P}}V_{L}^{\frac{1}{3}}} \propto \frac{1}{\sqrt{f_{P}}V_{L}^{\frac{1}{3}}}$$

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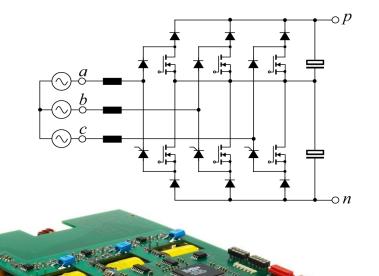
Remark – Natural Conv. Thermal Limit (1)

- Example of Highly-Compact 3-Φ PFC Rectifier Nat. Conv. Cooling of Inductors and EMI Filter Semiconductors Mounted on Cold Plate

 P_0 = 10 kW U_N = 230V_{AC}±10% f_N = 50Hz or 360...800Hz U_0 = 800V_{DC}

f_p= 250kHz

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→ Systems with f_p = 72/250/500/1000kHz → Factor 10 in f_p - Factor 2 in Power Density



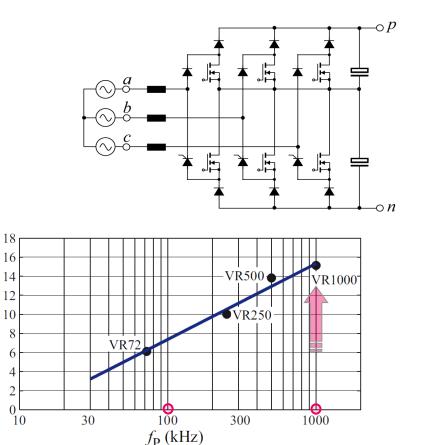
Remark – Natural Conv. Thermal Limit (2)

 ρ (kW/dm³)

- Example of Highly-Compact 3-**PFC** Rectifier Nat. Conv. Cooling of Inductors and EMI Filter Semiconductors Mounted on Cold Plate



f_P= 250kHz



 $\star \rho = 10 \text{ kW/dm}^3 @ \eta = 96.2\%$

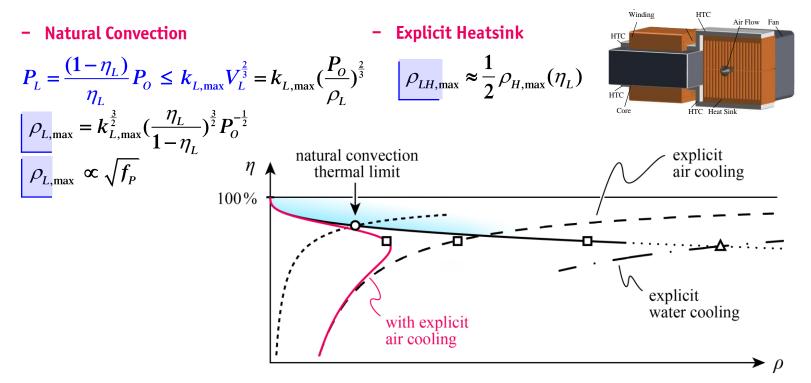
→ Systems with f_p = 72/250/500/1000kHz → Factor 10 in f_p - Factor 2 in Power Density

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• η - ρ -Characteristic of Inductor (4)

- Natural Convection Heat Transfer Seriously Limits Allowed Inductor Losses
- Higher Power Density Through Explicit Inductor Heatsink

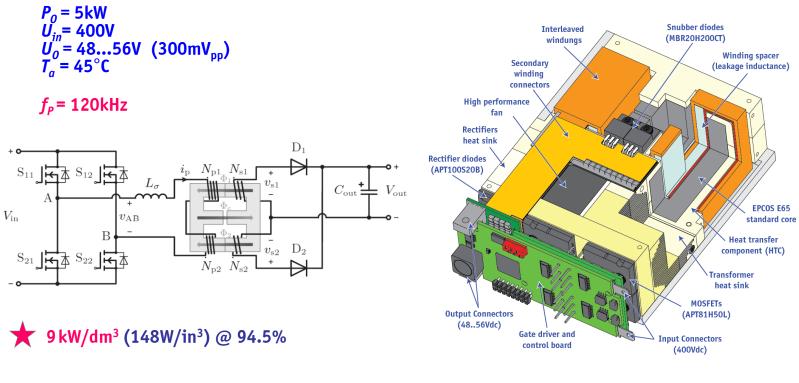


→ Heat Transfer Coefficients k_L and α_L Dependent on Max. Surface Temp. / Heatsink Temp. → Water Cooling Facilitates Extreme (Local) Power Densities



Remark – Example for Explicit Heatsink for Magn. Component

- Phase-Shift Full-Bridge Isolated DC/DC Converter with Current-Doubler Rectifier
- Heat Transfer Component (HTC) & Heatsink for Transformer Cooling Magn. Integration of Current-Doubler Inductors







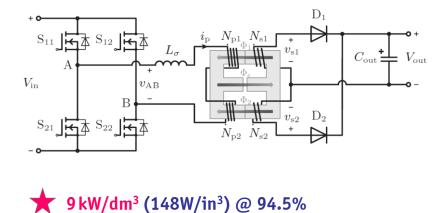
Remark – Example for Explicit Heatsink for Magn. Component

- Phase-Shift Full-Bridge Isolated DC/DC Converter with Current-Doubler Rectifier Heat Transfer Component (HTC) & Heatsink for Transformer Cooling Magn. Integration of Current-Doubler Inductors

$$P_o = 5kW$$

 $U_{in} = 400V$
 $U_o = 48...56V$ (300mV_{pp})
 $T_a = 45^{\circ}C$

 $f_{P} = 120 \text{kHz}$









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Overall Converter n-p-Characteristics

- **Combination of Storage/Heatsink/Auxiliary & Inductor Characteristics Sw. Frequ. Indicates Related Loss and Power Density Values** !

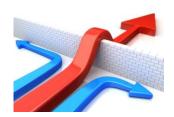
η η inductor inductor *f*_{P1} *1*_{P2} *f*_{P1} 1P2 $\int f_{\rm P} = 0$ • $\mathbf{O} f_{\mathrm{P}} = 0$ \bullet ••••• · () · · · 0 0 S $f_{\rm P1}$ ⊙ Ĵ_{P1} `*1*P1 TP1 JP2 $f_{\rm P2} > f_{\rm P1}$ $\Box f_{P2}$ $f_{\rm P2} > f_{\rm P1}$ storage, heatsink, storage, aux. supply heatsink, aux. supply ρ $\blacktriangleright \rho$ ≻

→ Low Sw. Losses / High Sw. Frequ. / Small Heatsink / Small Ind. / High Total Power Density → High Sw. Losses / Low Sw. Frequ. / Large Heatsink / Large Ind. / Low Total Power Density



Low Semiconductor Sw. Losses

High Semiconductor Sw. Losses



_ Reduction of Inductor Requirement

 $\begin{array}{l} \rightarrow & \text{Parallel Interleaving} \\ \rightarrow & \text{Series Interleaving} \end{array}$



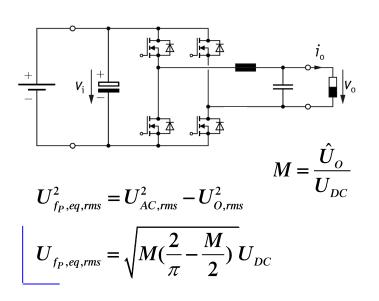


Inductor Volt-Seconds / Size

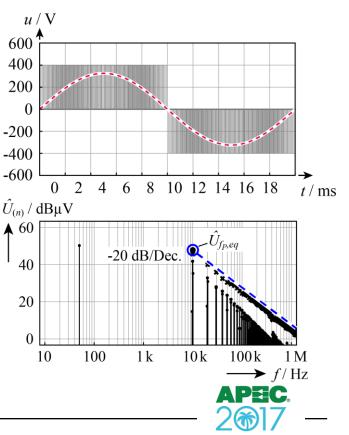
- Inductor Volt-Seconds are Determining the Local Flux Density Ampl. Output Inductor has to be Considered Part of the EMI Filter

$$\Delta \hat{B} \propto \frac{T_P U_{DC}}{A_E} \propto \frac{U_{DC}}{f_P A_E}$$

- Multi-Level Converters Allow to Decrease Volt-Seconds by Factor of N²
- Calculation of Equivalent Noise Voltage @ Sw. Frequency (2nd Bridge Leg w. Fund. Frequ.)

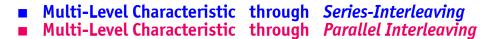


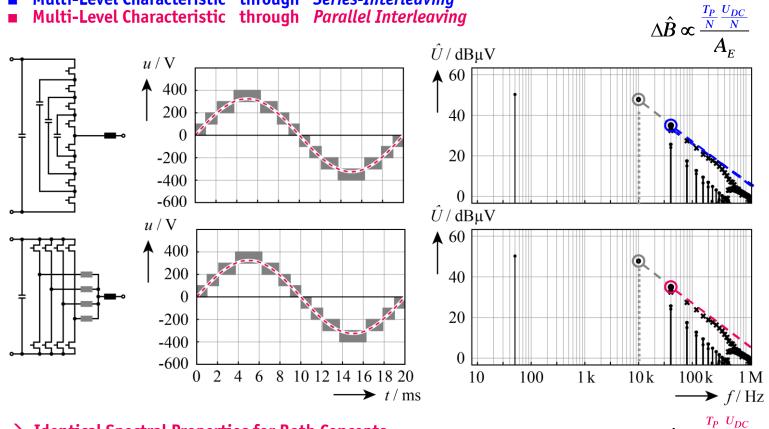
 \rightarrow EMI Filter Design Can be Based on Equiv. Noise Voltage



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Reduction of Inductor Volt-Seconds / Size





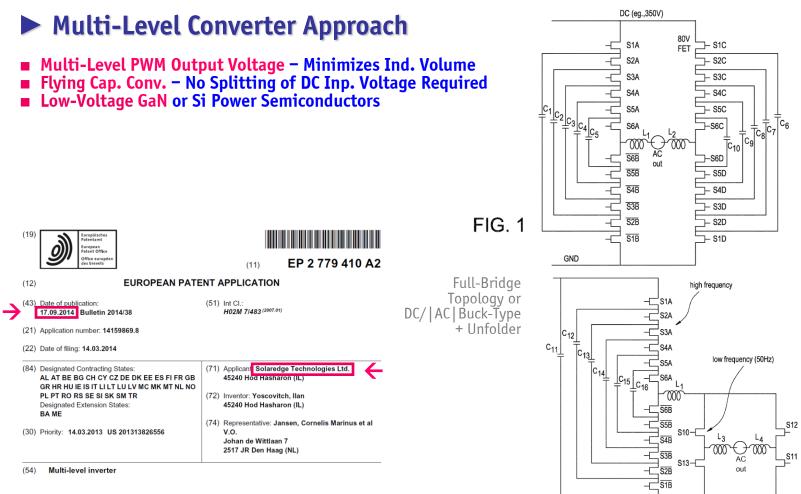
 \rightarrow Identical Spectral Properties for Both Concepts \rightarrow Series Interleaving Avoids Coupling Inductor of Parallel Interleaving !

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 $\Delta \hat{B} \propto \frac{\dot{N}}{N}$

 A_{E}

APEC



→ Basic Patent on FCC Converter – Th. Meynard (1991) ! FIG. 4



Transformers

Optimal Operating Frequency Example of MF/MV Transformer

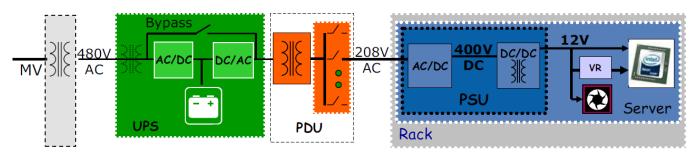




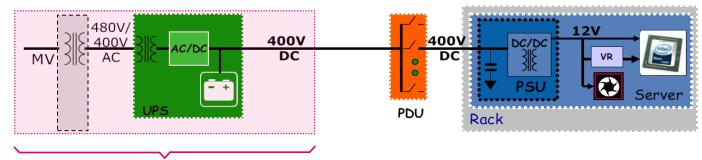
Future Direct MV Supply of 400V DC Distribution of Datacenters

- Reduces Losses & Footprint / Improves Reliability & Power Quality Unidirectional Multi-Cell Solid-State Transformer (SST)
- AC/DC and DC/DC Stage per Cell, Cells in Input Series / Output Parallel Arrangement
- **Conventional US 480V**_{AC} **Distribution**





Facility-Level 400 V_{pc} Distribution

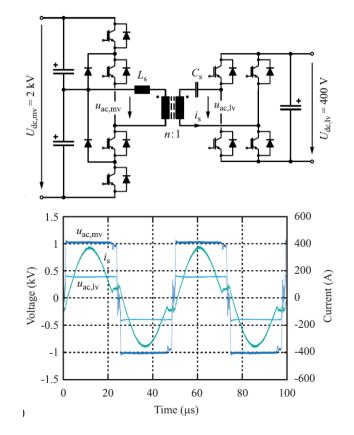


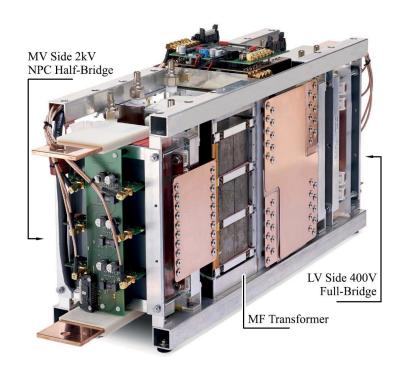
 \rightarrow Unidirectional SST / Direct 6.6kV AC \rightarrow 400V DC Conversion



Example of a 166kW/20kHz SST DC/DC Converter Cell

- Half-Cycle DCM Series Resonant DC-DC Converter
- Medium-Voltage Side 2kV
 - ı Low-Voltage Side 400V

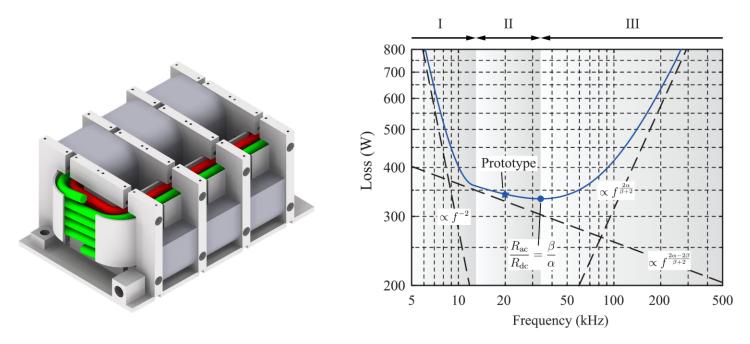






MF Transformer Design

- DoF Electric (# of Turns & Op. Frequ.) / Geometric / Material (Core & Wdg) Parameters Cooling / Therm. Mod. of Key Importance / Anisotr. Behavior of Litz Wire / Mag. Tape 20kHz Operation Defined by IGBT Sw. Losses / Fixed Geometry

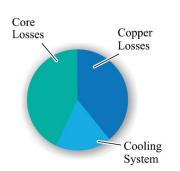


→ Region I: Sat. Limited / Min. Loss @ $P_c/P_W = 2/\beta (R_{AC}/R_{DC} = \beta/\alpha)$ / Region III: Prox. Loss Domin. → Heat Conducting Plates between Cores and on Wdg. Surface / Top/Bottom H₂O-Cooled Cold Plates

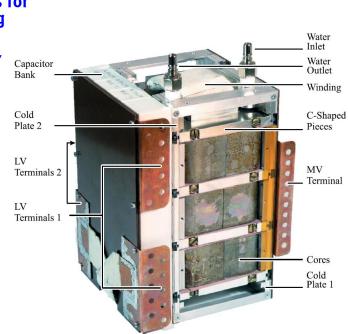


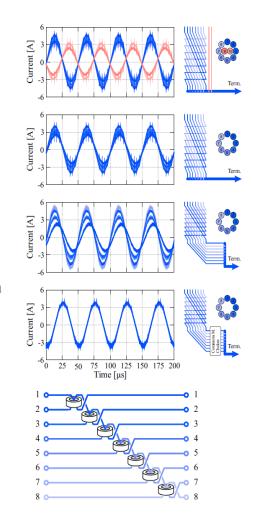
MF Transformer Prototype

- **Power Rating** 166 kW 99.5%
- Efficiency
- **Power Density** 44 kW/dm³
- Nanocrystalline Cores with 0.1mm Airgaps between Parallel Cores for -**Equal Flux Partitioning**
- Litz Wire (10 Bundles, 950 x 71µm Each) with CM Chokes for -**Equal Current** Partitioning



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Calculation of Converter η - ρ -Performance Limits

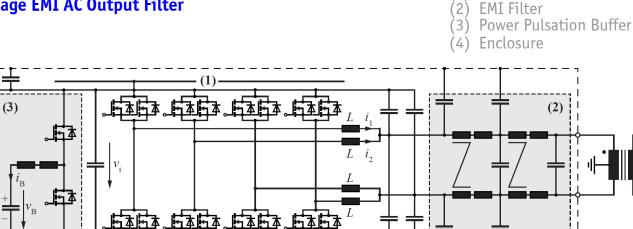
Google Little Box Challenge Ultra-Efficient $3-\Phi$ PFC Rectifier





Selected Converter Topology

- Interleaving of 2 Bridge Legs per Phase Active DC-Side Buck-Type Power Pulsation Buffer
- 2-Stage EMI AC Output Filter



- → ZVS of All Bridge Legs @ Turn-On/Turn-Off in Whole Operating Range (4D-TCM-Interleaving)
 → Heatsinks Connected to DC Bus / Shield to Prevent Cap. Coupling to Grounded Enclosure

(4)



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Heat Sink

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High Frequency Inductors (1)

- Multi-Airgap Inductor with Multi-Layer Foil Winding Arrangement Minim. Prox. Effect
- Very High Filling Factor / Low High Frequency Losses Magnetically Shielded Construction Minimizing EMI Intellectual Property of F. Zajc / Fraza
- L= 10.5µH
- 2 x 8 Turns

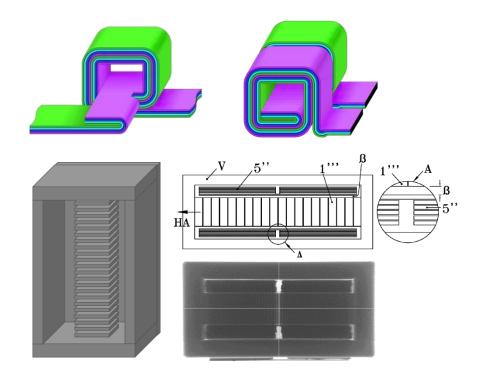
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- 24 x 80µm Airgaps
 Core Material DMR 51 / Hengdian
 0.61mm Thick Stacked Plates

- 20 μm Copper Foil / 4 in Parallel
 7 μm Kapton Layer Isolation
 20mΩ Winding Resistance / Q≈600
 Terminals in No-Leakage Flux Area



Dimensions - 14.5 x 14.5 x 22mm³ \rightarrow

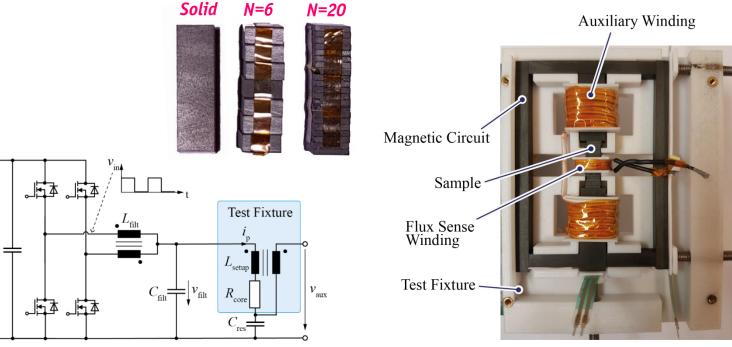






Multi-Airgap Inductor Core Loss Measurements (1)

- Investigated Materials DMR51, N87, N59
- 30 µm PET Foil with Double Sided Adhesive Between the Plates
 Varying Number N of Air Gaps Assembled from Thin Ferrite Plates
- Number of Air Gaps:



Sinusoidal Excitation with Frequencies in the Range of 250 kHz ...1MHz \rightarrow





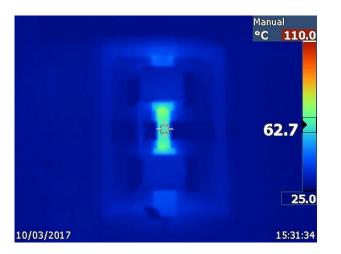
Multi-Airgap Inductor Core Loss Measurements (3)

- Losses in Sample Increasing Temperature
 Excitation with 100 mT @ 750 kHz

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Start @ T=35°C
Excitation Time = 90 s

Solid, $\Delta T = 27.7^{\circ}C$







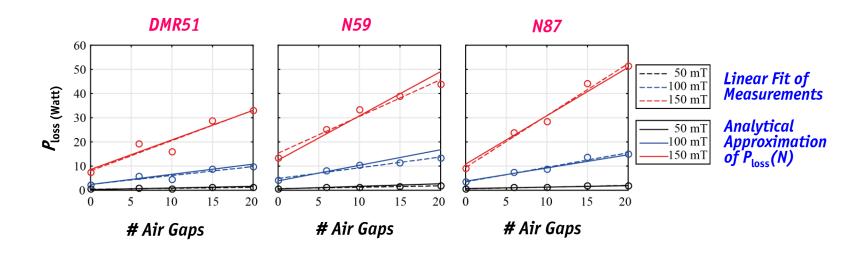




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Multi-Airgap Inductor Core Loss Approximation (2)

- Total Core Loss in Sample with Varying Air Gaps and Test Fixture
 Excitation © 500 kHz
- Excitation @ 500 kHz

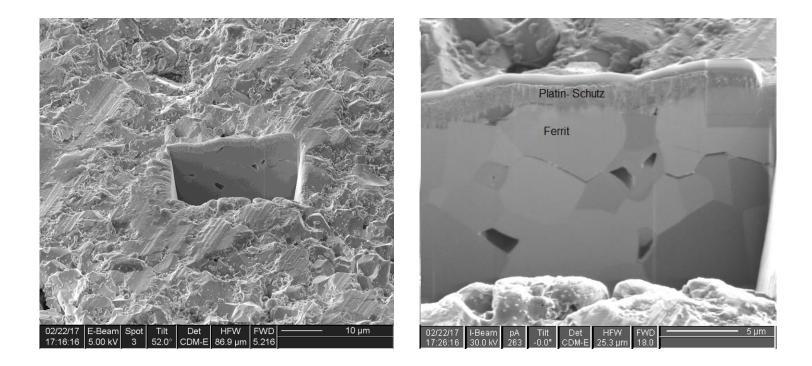


 $\Rightarrow \text{ Ext. of Steinmetz Eq.} \quad P_V = k_0 f^{\alpha} \hat{B}^{\beta} (V_C (\frac{A_S}{A_C})^{\beta} + V_S) + k_S f^{\alpha_S} \hat{B}^{\beta_S} \cdot N \cdot A_S \quad \text{Sufficiently Accurate}$



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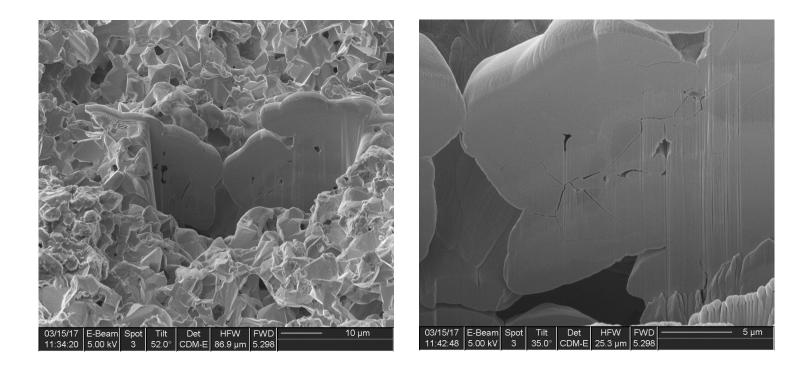
DMR 51 Untreated – FIB Preparation (1)







DMR 51 ETCHED – FIB Preparation (2)





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Little-Box 1.0 Prototype

- Performance
- 8.2 kW/dm³
- 96,3% Efficiency @ 2kW
 T_c=58°C @ 2kW
- **Design Details**

- 600V IFX Normally-Off GaN GIT
 Antiparallel SiC Schottky Diodes
 Multi-Airgap Ind. w. Multi-Layer Foil Wdg
 Triangular Curr. Mode ZVS Operation
 CeraLink Power Pulsation Buffer





Analysis of Potential Performance Improvement for "Ideal Switches" \rightarrow







Little-Box 1.0 Prototype

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 CeraLink Power Pulsation Buffer





→ Analysis of Potential Performance Improvement for "Ideal Switches"



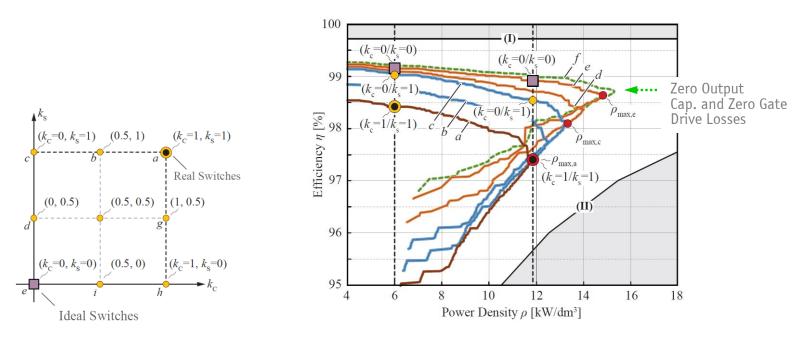
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Little Box 1.0 @ Ideal Switches (TCM)

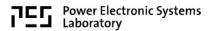
- Multi-Objective Optimization of Little-Box 1.0 (X6S Power Pulsation Buffer)
- Step-by-Step Idealization of the Power Transistors
- Ideal Switches: $k_c = 0$ (Zero Cond. Losses); $k_s = 0$ (Zero Sw. Losses)



→ Analysis of Improvement of Efficiency @ Given Power Density & Maximum Power Density → The Ideal Switch is NOT Enough (!)



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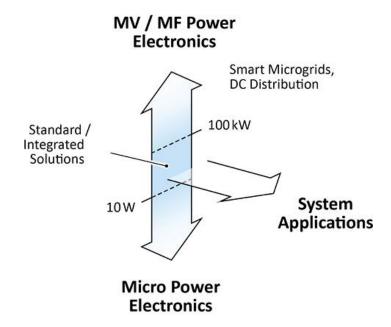
Source: whiskeybehavior.info





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Future Prospects of Power Electronics



Microelectronics Technology, Power Supply on Chip

\rightarrow Future Extension of Power Electronics Application Area



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Future Prospects of Magnetics

Side Conditions

- Magnetics are Basic Functional Elements (Filtering of Sw. Frequ. Power, Transformers)
- Non-Ideal Material Properties (Wdg. & Core) Result in Finite Magnetics Volume (Scaling Laws)
- Manufacturing Limits Performance (Strand & Tape Thickness etc.) @ Limited Costs

Option #1: Improve Modeling / Optimize Design

- Core Loss Modeling / Measurement Techniques (Cores and Complete Ind. / Transformer)
- Multi-Obj. Optimiz. Considering Full System
- Design for Manufacturing

Option #2: Improve Material Properties / Manufacturing

- Integrated Cooling
- PCB-Based Magnetics with High Filling Factor (e.g. VICOR)
- Advanced Locally Adapted Litz Wire / Low- μ Material (Distributed Gap) / Low HF-Loss Material

Option #3: Minimize Requirement

- Multi-Level Converters
- Magnetic Integration

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- Hybrid (Cap./Ind.) Converters

→ Magnetics/Passives-Centric Power Electronics Research Approach !













Thank You !





